

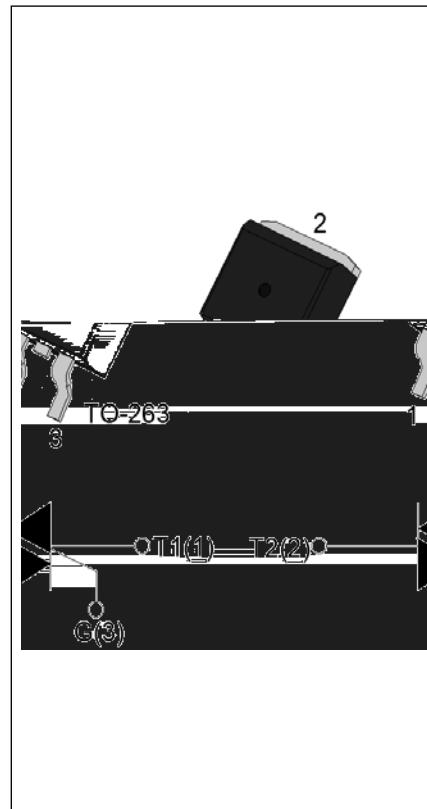


## T0410H-6E 4A TRIAC

Rev.A.1.0

## DESCRIPTION:

The T0410H-6E is a single phase AC switch. It has an ON/OFF function controlled by a pulse signal. It can be used in high voltage applications up to 150V. It can be driven through MCU I/O pins. T0263 is its lead frame.



## MAIN FEATURES

Symbol	Value	Unit
$I_T(\text{RMS})$	4	A
$V_{\text{DRM}} / V_{\text{RRM}}$	600	V
$I_{\text{GT}}$	10/10/10	mA

## ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
Storage temperature	$T_s$	-40-150	
Operating temperature	$T_j$	-40-150	
Repetitive peak -sine ( $T_j=25^\circ\text{C}$ )	$V_{\text{DRM}}$	600	V
Repetitive peak ( $T_j=25^\circ\text{C}$ )	$V_{\text{RRM}}$	600	V
RMS current ( $T_c = 137^\circ\text{C}$ )	$I_T(\text{RMS})$	4	A
Normal operating -sine (flat, $t_p=20\mu\text{s}$ , $T_j=25^\circ\text{C}$ )	$I_{\text{TSM}}$	40	A
Normal operating -sine (flat, $t_p=16.6\mu\text{s}$ , $T_j=25^\circ\text{C}$ )		44	
Inductive load ( $t_p=10\mu\text{s}$ , $j=25^\circ\text{C}$ )	$I^2t$	8	$\text{A}^2\text{s}$
Circuit current rate -sine ( $I_G=2 \times I_{\text{GT}}$ , $f=100\text{Hz}$ , $T_j=150^\circ\text{C}$ )	$dI/dt$	50	$\text{A}/\mu\text{s}$
Pulse current ( $t_p=20\mu\text{s}$ , $T_j=150^\circ\text{C}$ )	$I_{\text{GM}}$	4	A
Average power dissipation ( $T_j=150^\circ\text{C}$ )	$P_{\text{G}(AV)}$	1	W

T0410H-6E

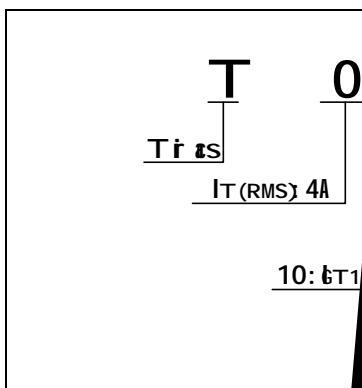
Peak power (P <sub>GM</sub> )	P <sub>GM</sub>	10	W
Peak voltage (T <sub>j</sub> =25°C - see Fig. 8)	V <sub>p</sub>	3	kV

ELECTRICAL CHARACTERISTICS (T<sub>j</sub>=25°C unless specified)

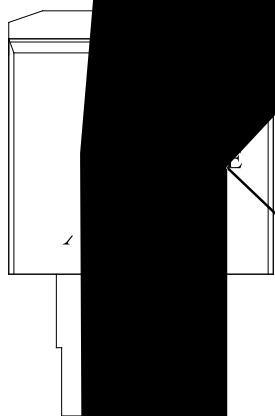
Symbol	Test Condition	Quadrant	Value		Unit
I <sub>GT</sub>	V <sub>D</sub> =12V R <sub>L</sub> =33Ω	- -	MAX .	10	mA
V <sub>GT</sub>		- -	MAX .	1	V
V <sub>GD</sub>	V <sub>D</sub> =V <sub>DRM</sub> T <sub>j</sub> =150°C R <sub>L</sub> =3.3K	- -	MIN .	0.2	V
I <sub>L</sub>	I <sub>G</sub> =1.2 <sub>GT</sub>	-	MAX .	20	mA
				35	
I <sub>H</sub>	I <sub>T</sub> =100mA		MAX .	20	mA
t <sub>on</sub>	I <sub>G</sub> =20mA I <sub>A</sub> =200mA I <sub>R</sub> =20mA T <sub>j</sub> =25°C		TYP .	2.5	μs
t <sub>off</sub>				25	A/μs

# T0410H-6E

## ORDERING INFORMATION



## MARKING



**T0410H-6E**

 **JieJie Microelectronics Co., Ltd.**

**FIG.1 Max output power RMS  
vs. Output Power**

**FIG.2: RMS output power  
vs. Output Power**

**FIG.7: Reliability & aging characteristics  
of chip**

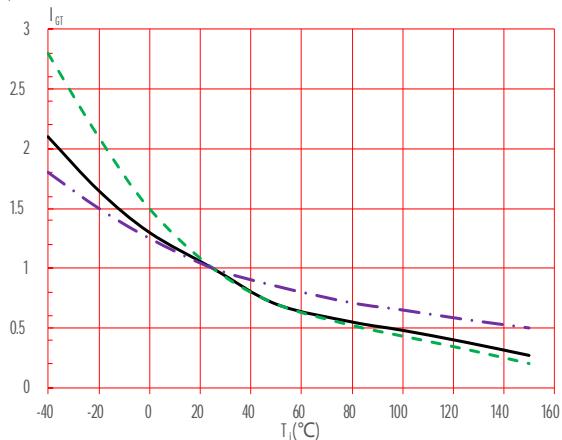
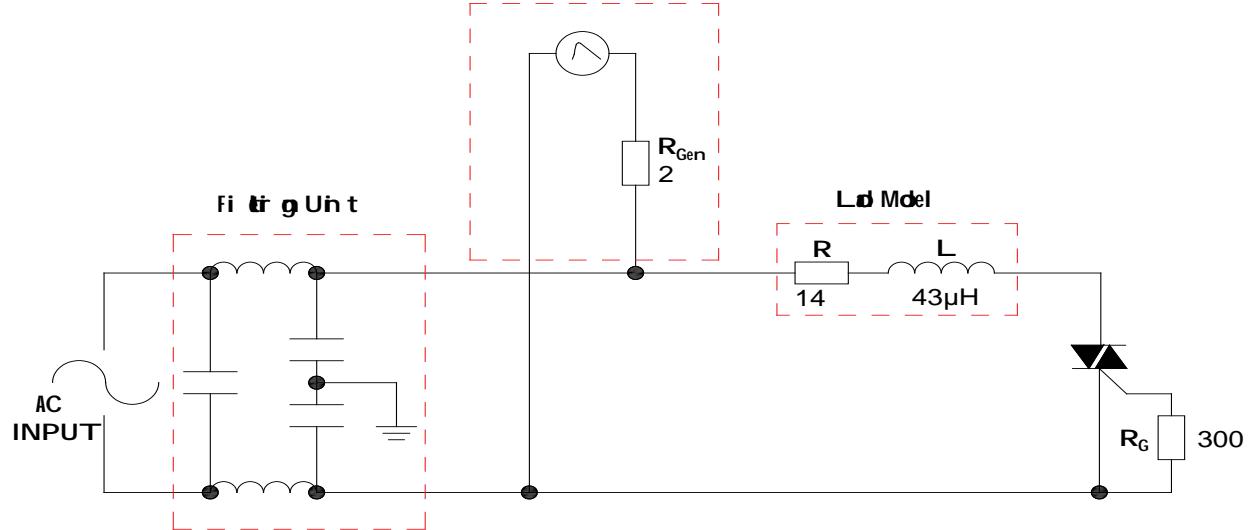


FIG. 8 Test circuit for浪涌耐压值

-61000-4-5 test

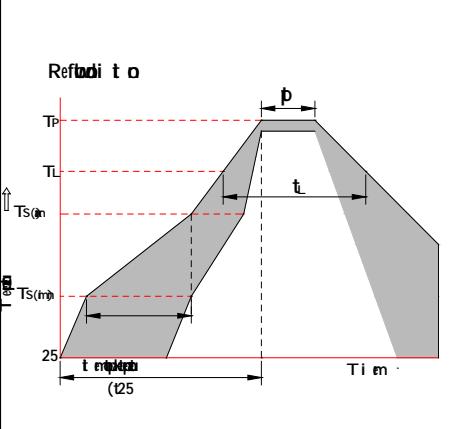
IEC61000-4-5 Standards

Surge Generator

1.2/50μS voltage surge  
8/20μS current surge

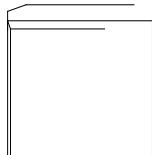
## SOLDERING PARAMETERS

Reflow soldering		Pb-Free alloy (or fine gold plating)
Pre-Heat	-TempMin(T <sub>min</sub> )	+150
	-TempMax(T <sub>max</sub> )	+200
	-Time(Min Max)	60-180 s
Rework		3 / sec. Max
T <sub>on</sub> or T <sub>L</sub> - Ramp rate		3 / sec. Max
Reflow	-Temp(T <sub>L</sub> )(Liquidation)	+217
	-Temp(t <sub>L</sub> )	60-150 s
PeakTemp(T <sub>p</sub> )		+260(+0/-5)
Time withstand data PeakTemp(T <sub>p</sub> )		20-40 s
Ramp-down rate		6 / sec. Max
Time 25 °C peakTemp(T <sub>p</sub> )		8 min Max
Dwell		+260



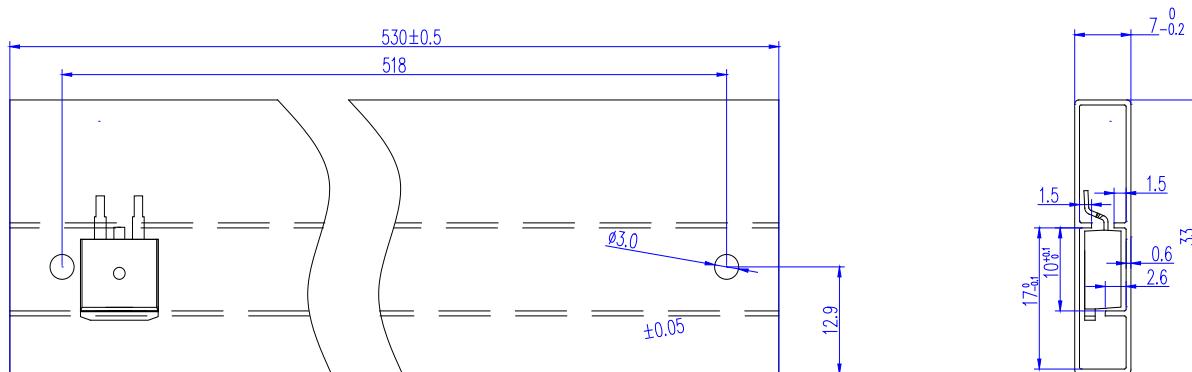
**T0410H-6E**

## PACKAGE MECHANICAL DATA

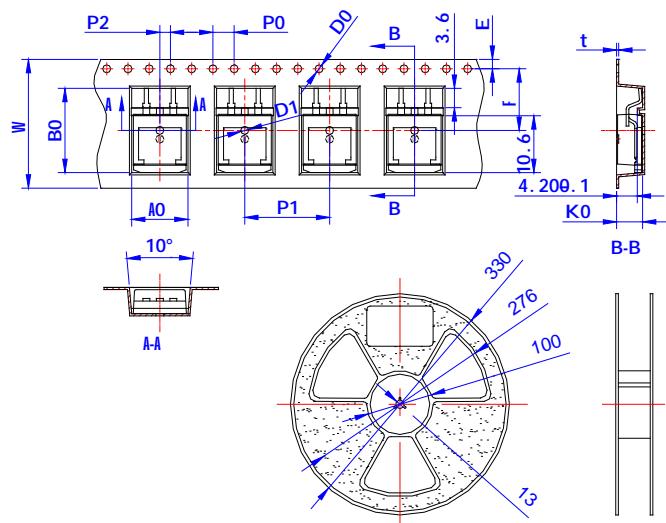


Ref.	Dimensions					
	Metric			Inches		
	Min	Typ	Max	Min	Typ	Max
A	9.90		10.20	0.390		0.402
B	14.70		15.80	0.579		0.622
C	9.40		9.60	0.37		0.378
D	2.40			0.094		
E	1.20		1.50	0.047		0.059
F	0.75		0.85	0.029		0.033
G			1.50			
H	4.40		4.70	0.173		0.185
J	2.30		2.70	0.091		0.106
K	0.38		0.55	0.015		0.022
L	0		0.25			
M	1.25		1.35			

## DELIVERY MODE



PACKAGE	OUTLINE	TUBE (PCS)	INNER BOX (PCS)	PER CARTON
TO263	TUBE	50	1,000	5,000



Ref.	Dimensions					
	Minor			Major		
	Min	Typ	Max	Min	Typ	Max
W	23.70	24.00	24.30	0.933	0.945	0.957
E	1.65	1.75	1.85	0.065	0.069	0.073
F	11.40	11.50	11.60	0.449	0.453	0.457
D0	-	1.50	1.60	-	0.059	0.063
D1	-	1.50	1.60	-	0.059	0.063
P0	3.90	4.00	4.10	0.154	0.157	0.161
P1	15.90	16.00	16.10	0.626	0.630	0.634
P2	1.90	2.00	2.10	0.075	0.079	0.083
M0	10.80	10.90	11.00	0.425	0.429	0.433
B0	16.20	16.30	16.40	0.638	0.642	0.646
K0	4.80	4.90	5.00	0.189	0.193	0.197
t	0.35	0.40	0.45	0.014	0.016	0.018

If you have any questions or comments, please feel free to contact us. Your feedback is very important to us.  
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